

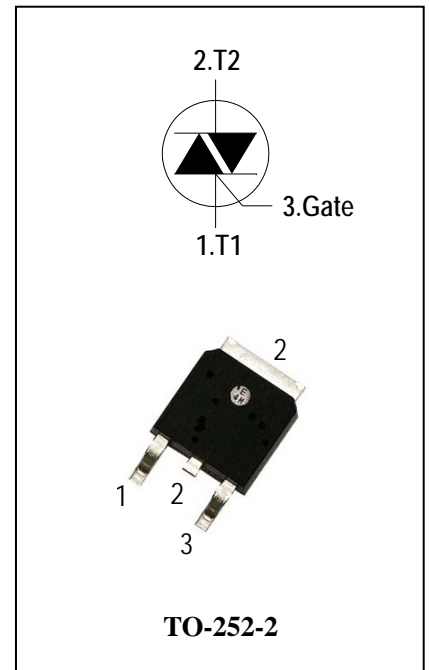
## 3 Quadrants Triacs

### General Description

High current density due to mesa technology . the ADT4C triac series is suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, Rectifier-fed DC inductive loads e.g.DC motors and solenoids , motor speed controllers.

### Features

- ◆ Repetitive Peak Off-State Voltage: 600Vand800V
- ◆ R.M.S On-State Current (  $I_{T(RMS)} = 4A$  )
- ◆ High Commutation dv/dt
- ◆ These Devices are Pb-Free and are RoHS Compliant



### Absolute Maximum Ratings

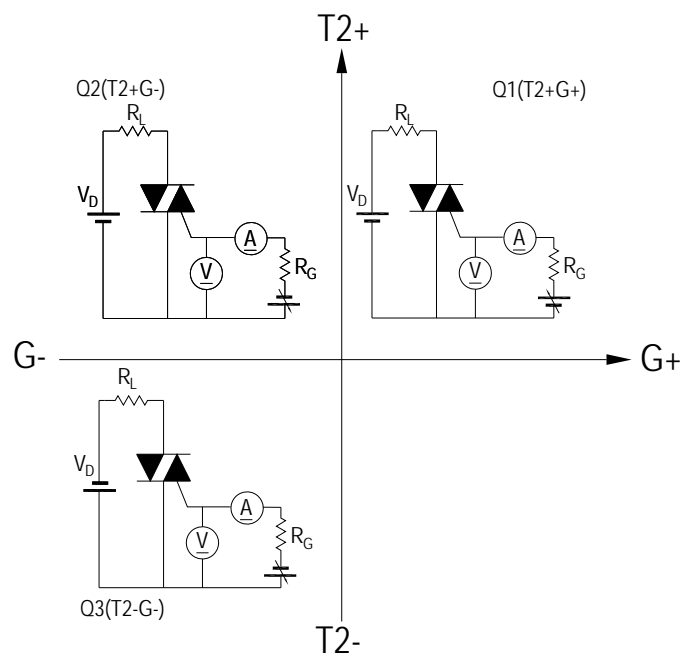
Symbol	Items	Conditions	Ratings	Unit
$V_{DRM}$ $V_{RRM}$	Repetitive Peak Off-State Voltage	$T_j = 25^\circ C$	ADT4C60E 600 ADT4C80E 800	V V
$I_{T(RMS)}$	R.M.S On-State Current	$T_C = 110^\circ C$	4	A
$I_{TSM}$	Surge On-State Current	$t_p=20ms(50Hz)/t_p=16.7ms(60Hz)$	30/32	A
$I^2t$	$I^2t$ for fusing	$t_p=10ms$	5.1	$A^2s$
dI/dt	Critical rate of rise of on-state current	$F = 120 Hz$ $T_j = 125^\circ C$ $I_G = 2 \times I_{GT}$ , $t_r \leq 100 ns$	50	$A/\mu s$
$I_{GM}$	Peak Gate Current	$t_p = 20 \mu s$ $T_j = 125^\circ C$	2	A
$P_{G(AV)}$	Average Gate Power Dissipation( $T_j=125^\circ C$ )		0.5	W
$P_{GM}$	Peak Gate Power Dissipation( $t_p=20\mu s, T_j=125^\circ C$ )		5	W
$T_j$	Operating Junction Temperature		- 40 ~ 125	$^\circ C$
$T_{STG}$	Storage Temperature		- 40 ~ 150	$^\circ C$



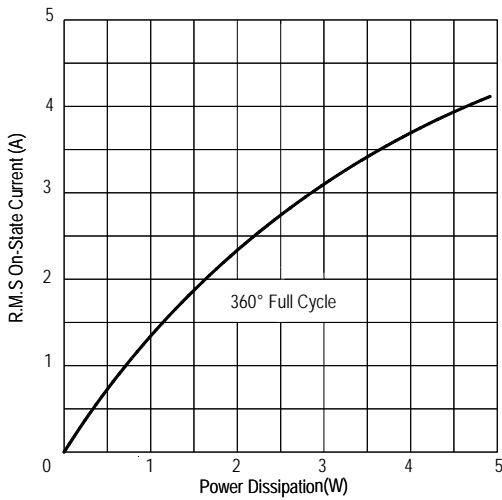
## Electrical Characteristics ( $T_j = 25^\circ\text{C}$ unless otherwise specified )

Symbol	Items		Conditions		ADT4C60E/80E				Unit
					T	S	Blank	B	
$I_{DRM}$ $I_{RRM}$	Peak Forward Reverse Blocking Current		$V_{DRM} = V_{RRM}, T_j = 25^\circ\text{C}$	Max.	5				$\mu\text{A}$
			$V_{DRM} = V_{RRM}, T_j = 125^\circ\text{C}$		1				$\text{mA}$
$V_{TM}$	Peak On-State Voltage		$I_{TM} = 5.5\text{A}, t_p = 380 \mu\text{s}$	Max.	1.6				$\text{V}$
$V_{GD}$	Q1-Q2-Q3	Non-Trigger Gate Voltage	$V_D = V_{DRM} \quad R_L = 3.3 \text{ k}\Omega$ $T_j = 125^\circ\text{C}$	Min.	0.2				$\text{V}$
$V_{GT}$	Q1-Q2-Q3	Gate Trigger Voltage	$V_D = 12\text{V}, R_L = 33\Omega$	Max.	1.3				$\text{V}$
$I_{GT}$	Q1-Q2-Q3	Gate Trigger Current		Max.	5	10	35	50	$\text{mA}$
$I_H$	Q1-Q2-Q3	Holding Current	$I_T = 0.1\text{A}$	Max.	10	15	40	60	$\text{mA}$
$I_L$	Q1-Q3	Latching Current	$I_G = 1.2 I_{GT}$	Max.	10	25	50	70	$\text{mA}$
	Q2				15	30	70	80	
$dV/dt$	Critical Rate of Rise of Off-State Voltage		$V_D = 2/3V_{DRM}$ gate open $T_j = 125^\circ\text{C}$	Min.	20	40	400	1000	$\text{V}/\mu\text{s}$
$(dV/dt)_c$	Rate of Change of Commutating Current,		$(dI/dt)_c = -1.7\text{A}/\text{ms}$ $T_j = 125^\circ\text{C}$	Min.	0.5	1	10	25	$\text{V}/\mu\text{s}$
$R_{th(j-c)}$	Junction to case (AC)			Max.	3.0				$^\circ\text{C}/\text{W}$
$R_{th(j-a)}$	Junction to ambient(Copper surface under tab: $S=0.5\text{cm}^2$ )			Max.	70				$^\circ\text{C}/\text{W}$

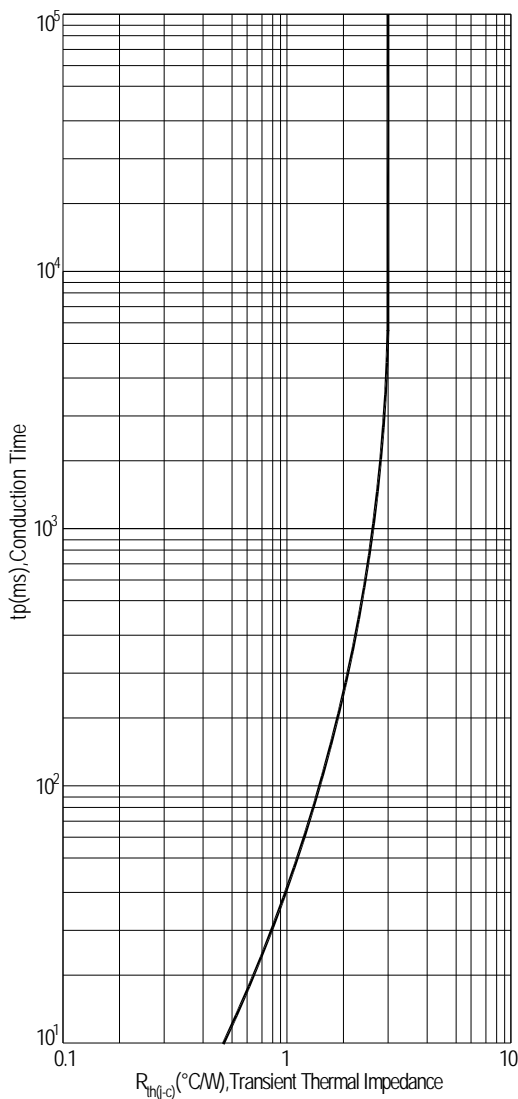
**FIG.1:Triac quadrant are defined and the gate trigger test circuit**



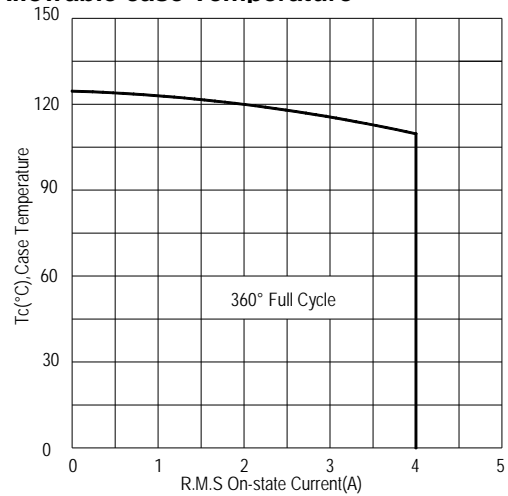
**FIG.2: Maximum on-state power dissipation**



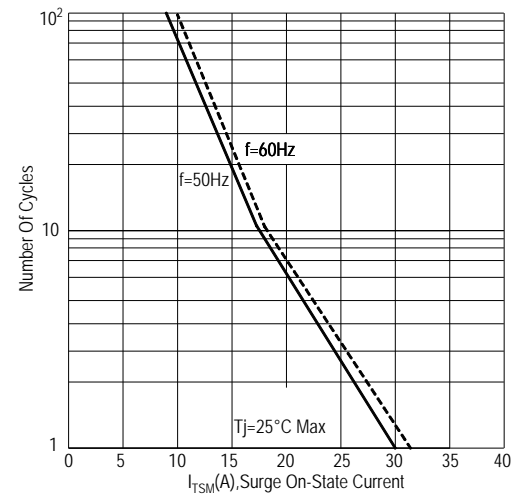
**FIG.4: Maximum transient thermal impedance**



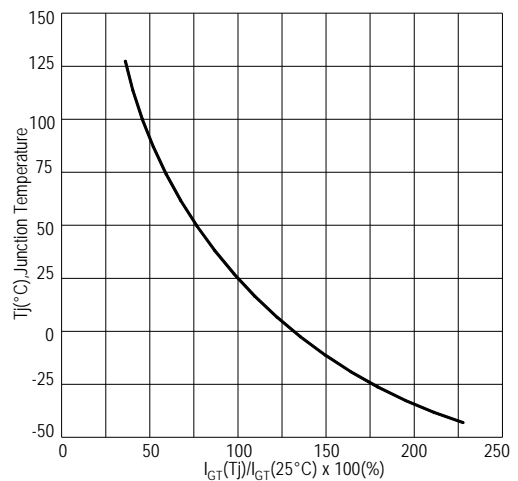
**FIG.3: Typical RMS on-state current VS Allowable case Temperature**



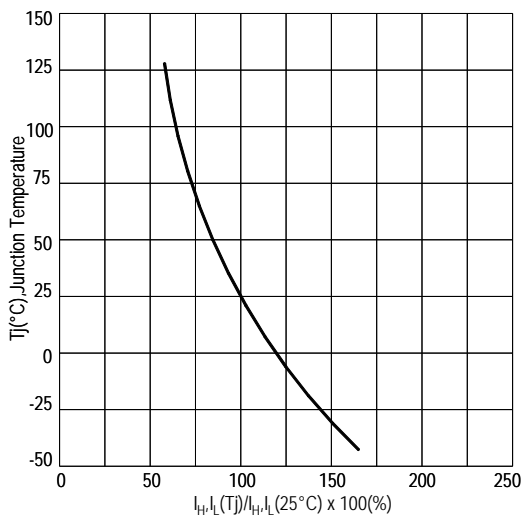
**FIG.5: Rated surge on-state current ( Non-Repetitive)**



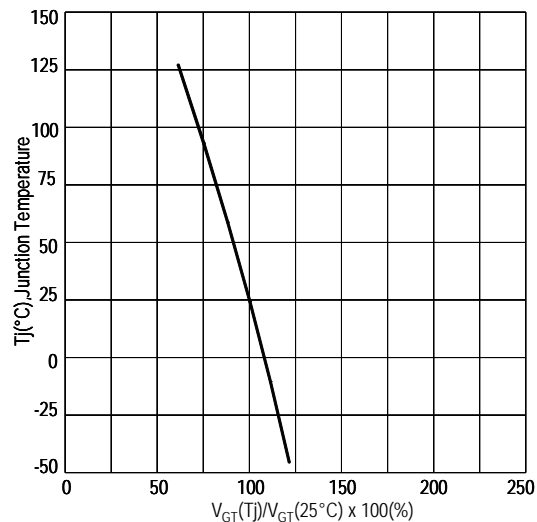
**FIG.6: Gate trigger current VS Junction temperature**



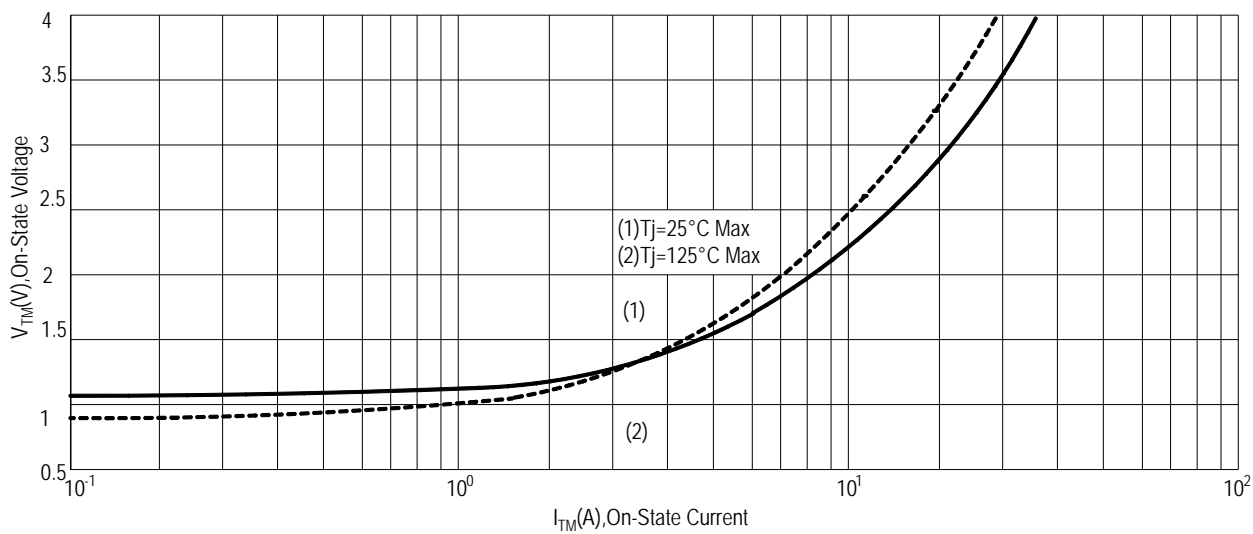
**FIG.7: Holding current and Latching current VS Junction temperature**



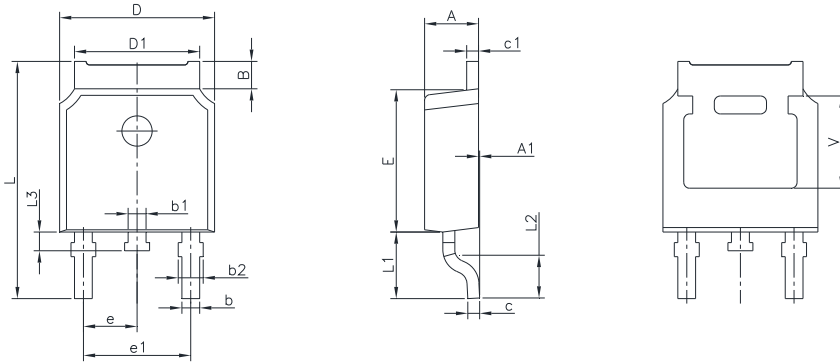
**FIG.8: Gate trigger voltage VS Junction temperature**



**FIG.9: On-state characteristics(Max)**



## PACKAGE MECHANICAL DATA TO-252-2 Package Dimension



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
B	1.070	1.220	0.042	0.048
b	0.720	0.850	0.028	0.033
b1	0.720	0.850	0.028	0.033
c	0.450	0.620	0.017	0.024
c1	0.450	0.620	0.017	0.024
D	6.350	6.650	0.250	0.262
D1	5.200	5.400	0.205	0.213
E	5.900	6.200	0.232	0.244
e	2.300 TYP.		0.091 TYP.	
e1	4.500	4.700	0.177	0.185
L	9.500	10.60	0.374	0.396
L1	2.550	2.900	0.100	0.114
L2	1.400	1.780	0.055	0.070
L3	0.600	0.900	0.024	0.035
V	3.950 REF.		0.155 REF.	

### Making Diagram

ADV:Logo  
ADT4C80ET:Part number  
X:Internal control code  
H:Halogen Free

AD T 4 C 80 E T(S)(B)

ADVANCED	Sensitivity and type:
Internal control code	T=5mA
Current:4=4A	S=10mA
Quadrant:C=3Q	Blank=35mA
Voltage:60=600V 80=800V	B=50mA
	Package explain:D=TO-252-2

### Ordering information

Part number	Package	Marking	Packing	Quantity
ADT4C60E#	TO-252-2	ADT4C60E#	Tube	80pcs
			Embossed tape	2500pcs
ADT4C80E#	TO-252-2	ADT4C80E#	Tube	80pcs
			Embossed tape	2500pcs

Note:# = Gate Trigger Current Sensitivity and type

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